



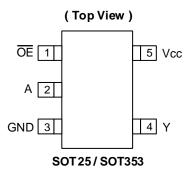


SINGLE BUFFER GATE WITH 3-STATE OUTPUT

Description

The 74AHCT1G125Q is an automotive compliant, single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable (\overline{OE}) pin. The device is designed for operation with a power supply range of 4.5V to 5.5V.

Pin Assignments



Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 4.5V to 5.5V
- ±8mA Output Drive at 4.5V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHCT1G125Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Applications

- General Purpose Logic
- Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

Notes:

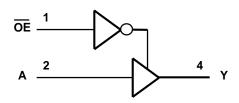
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

| Pin Name | Description |
|----------|----------------|
| ŌĒ | Output Enable |
| А | Data Input |
| GND | Ground |
| Υ | Data Output |
| Vcc | Supply Voltage |

Logic Diagram



Function Table

| Inp | Output | |
|-----|--------|---|
| ŌĒ | Α | Y |
| L | Н | Н |
| L | L | L |
| Н | Х | Z |

Absolute Maximum Ratings (Notes 4 & 5)

| Symbol | Description | Rating | Unit |
|------------------|--|-------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | kV |
| ESD CDM | Charged Device Model ESD Protection | 1 | kV |
| Vcc | Supply Voltage Range | -0.5 to 6.5 | V |
| Vı | Input Voltage Range | -0.5 to 6.5 | V |
| Vo | Voltage Applied to Output in High or Low State | -0.5 to Vcc + 0.5 | V |
| lıĸ | Input Clamp Current V _I < 0 | -20 | mA |
| Іок | Output Clamp Current (Vo < 0 or Vo > Vcc) | ±20 | mA |
| lo | Continuous Output Current (Vo = 0 to Vcc) | ±25 | mA |
| Icc | Continuous Current Through Vcc | 75 | mA |
| Ignd | Continuous Current Through GND | -75 | mA |
| TJ | Operating Junction Temperature | -40 to +150 | °C |
| T _{STG} | Storage Temperature | -65 to +150 | °C |
| PD | Total Power Dissipation (Note 6) | 250 | mW |

Notes:

- 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should
- 5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.
- 6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T.J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

| Symbol | P | arameter | Min | Max | Unit |
|-----------------|------------------------------------|------------------------|-----|------|------|
| Vcc | Operating Voltage | _ | 4.5 | 5.5 | V |
| V _{IH} | High-Level Input Voltage | $V_{CC} = 5V \pm 0.5V$ | 2.0 | | V |
| VIL | Low-Level Input Voltage | $Vcc = 5V \pm 0.5V$ | _ | 0.8 | V |
| Vı | Input Voltage | | 0 | 5.5 | V |
| Vo | Output Voltage | | 0 | Vcc | V |
| Іон | High-Level Output Current | $Vcc = 5V \pm 0.5V$ | _ | -8 | mA |
| loL | Low-Level Output Current | $Vcc = 5V \pm 0.5V$ | _ | 8 | mA |
| Δt/ΔV | Input Transition Rise or Fall Rate | $V_{CC} = 5V \pm 0.5V$ | _ | 20 | ns/V |
| TA | Ambient Temperature | _ | -40 | +125 | °C |

Note:

Electrical Characteristics (All typical values are at V_{CC} = 5V, T_A = +25°C.)

| 0 | D | Table Oans did as a | V | | +25°C | | -40°C to | +85°C | -40°C to | +125°C | 1124 |
|--------|------------------------------|--|-----------|------|-------|------|----------|-------|----------|--------|------|
| Symbol | Parameter | Test Conditions | Vcc | Min | Тур | Max | Min | Max | Min | Max | Unit |
| Mari | High Level Output | VI = VIH or VIL IOH = -50µA | 4.5V | 4.4 | 4.5 | _ | 4.4 | 1 | 4.4 | 1 | V |
| Vон | Voltage | VI = VIH or VIL IOH = -8mA | 4.5V | 3.94 | _ | _ | 3.8 | 1 | 3.70 | 1 | V |
| | Low Level Output | V _I = V _{IH} or V _{IL} I _{OL} = 50μA | 4.5V | _ | 0 | 0.1 | 1 | 0.1 | - | 0.1 | V |
| Vol | Voltage | VI = VIH OR VIL IOL = 8mA | 4.5V | _ | _ | 0.36 | 1 | 0.44 | - | 0.55 | V |
| loz | Z State Leakage Current | V _I = 5.5V or GND V _O = 0 to 5.5V | 5.5V | _ | _ | 0.25 | 1 | 2.5 | - | 10 | μΑ |
| lı | Input Current | V _I = 5.5V or GND | 0 to 5.5V | _ | _ | ±0.1 | _ | ±1 | _ | ±2 | μΑ |
| ΔΙσο | Additional Supply Current | Per input pin; V _I = 3.4V; other inputs at V _{CC} or GND; I _O = 0 | 5.5V | _ | _ | 1.35 | | 1.5 | 1 | 1.5 | mA |
| Icc | Supply Current | V _I = 5.5V or GND I _O = 0 | 5.5V | _ | _ | 1 | | 10 | | 40 | μΑ |
| Cı | Input Capacitance | VI = Vcc or GND | 5.5V | _ | 1.5 | 10 | _ | 10 | _ | 10 | рF |

^{7.} Unused inputs should be held at $\ensuremath{V_{\text{CC}}}$ or Ground.



Package Characteristics

| Symbol | Parameter | Package | Test Conditions | Min | Тур | Max | Unit |
|--------|---------------------|---------|-----------------|-----|-----|-----|------|
| 0 | Thermal Resistance | SOT25 | Note 0 | 1 | 184 | _ | 9044 |
| ALθ | Junction-to-Ambient | SOT353 | Note 8 | - | 385 | _ | °C/W |
| 0 | Thermal Resistance | SOT25 | Nata 0 | _ | 62 | _ | 0044 |
| θυς | Junction-to-Case | SOT353 | Note 8 | - | 164 | _ | °C/W |

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

 V_{CC} = 5V ± 0.5V (See Figure 1, Typical values at V_{CC} = 5V.)

| Parameter | From | То | Test | +25°C | | -40°C to +85°C -40°C to +125°C | | +125°C | Unit | | |
|-----------|---------|----------|-----------------------|-------|-----|--------------------------------|-----|--------|------|------|-------|
| Parameter | (Input) | (Output) | Conditions | Min | Тур | Max | Min | Max | Min | Max | Offic |
| 4 | ۸ | V | C _L = 15pF | 1.0 | 3.4 | 5.5 | 1.0 | 6.5 | 1.0 | 7.0 | ns |
| tpD | A | Ţ | C _L = 50pF | 1.0 | 4.8 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| 4 | | V | C∟= 15pF | 1.0 | 3.9 | 5.1 | 1.0 | 6.0 | 1.0 | 6.5 | ns |
| tEN | OE | ī | C _L = 50pF | 1.0 | 5.1 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| 4 | | V | C∟= 15pF | 1.0 | 4.5 | 6.8 | 1.0 | 8.0 | 1.0 | 8.5 | ns |
| tDIS | OE | Ţ | C _L = 50pF | 1.0 | 6.1 | 8.8 | 1.0 | 10.0 | 1.0 | 11.0 | ns |

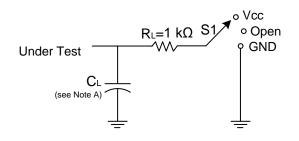
Operating Characteristics

 $T_A = +25^{\circ}C$

| | Parameter | Test Conditions | Тур | Unit |
|-----|-------------------------------|---|-----|------|
| СРД | Power Dissipation Capacitance | $V_{CC} = 5.0V$, $f = 1MHz$ $C_L = 50pF$ $V_I = GND$ to V_{CC} | 11 | pF |

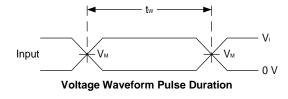


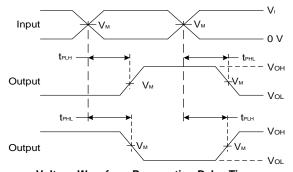
Measurement Information



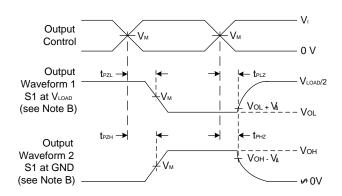
| Test | S 1 |
|-----------|------------|
| tplh/tphl | Open |
| tplz/tpzl | Vload |
| tphz/tpzh | GND |

| V | Inp | uts | Voc | V | 0: | D. | V/A | |
|---------|-----------|--------------------------------|------|-------|------|-----|------------|--|
| Vcc | Vı | t _R /t _F | Vм | VLOAD | CL | R∟ | V Δ | |
| 5V±0.5V | GND to 3V | ≤2.5ns | 1.5V | Vcc | 15pF | 1kΩ | 0.3V | |
| 5V±0.5V | GND to 3V | ≤2.5ns | 1.5V | Vcc | 50pF | 1kΩ | 0.3V | |





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

A. Includes test lead and test apparatus capacitance. Notes:

B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
 C. Inputs are measured separately one transition per measurement.

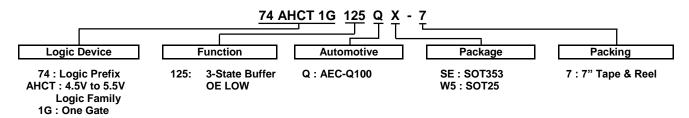
D. t_{PLZ} and t_{PHZ} are the same as t_{DIS} .

E. t_{PZL} and t_{PZH} are the same as t_{EN} .

F. t_{PLH} and t_{PHL} are the same as t_{PD} .



Ordering Information (Note 9)



| Part Number | Package | Package | Package Size | 7" Tape | and Reel |
|------------------|---------|-----------------|--|------------------|--------------------|
| Fait Number | Code | (Notes 10 & 11) | Fackage Size | Quantity | Part Number Suffix |
| 74AHCT1G125QSE-7 | SE | SOT353 | 2.15 mm \times 2.1 mm \times 1.1 mm 0.65 mm lead pitch | 3000/Tape & Reel | -7 |
| 74AHCT1G125QW5-7 | W5 | SOT25 | 3.0 mm \times 2.8 mm \times 1.2 mm 0.95 mm lead pitch | 3000/Tape & Reel | -7 |

Notes:

For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
 Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
 The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information

(Top View)

XXX

XXX: Identification Code

: Year 0~9

: Week: A~Z 1~26 week a~z 27~52 week

z represents week 52 and 53

X: A~ Z: Internal Code

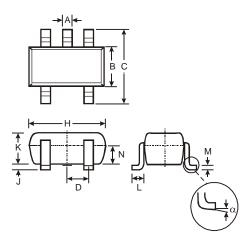
SOT25 / SOT353

| Part Number | Package | Identification Code |
|------------------|---------|---------------------|
| 74AHCT1G125QW5-7 | SOT25 | ZYQ |
| 74AHCT1G125QSE-7 | SOT353 | ZYQ |



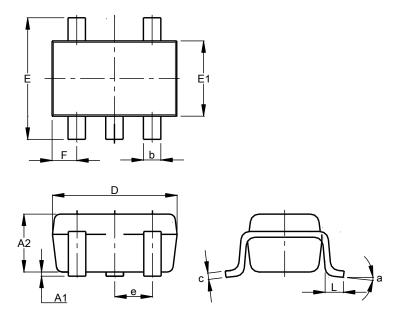
Package Outline Dimensions

(1) Package Type: SOT25



| SOT25 | | | | | |
|----------------------|-------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.35 | 0.50 | 0.38 | | |
| В | 1.50 | 1.70 | 1.60 | | |
| С | 2.70 | 3.00 | 2.80 | | |
| D | - | - | 0.95 | | |
| Н | 2.90 | 3.10 | 3.00 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| K | 1.00 | 1.30 | 1.10 | | |
| L | 0.35 | 0.55 | 0.40 | | |
| M | 0.10 | 0.20 | 0.15 | | |
| N | 0.70 | 0.80 | 0.75 | | |
| α | 0° | 8° | - | | |
| All Dimensions in mm | | | | | |

(2) Package Type: SOT353



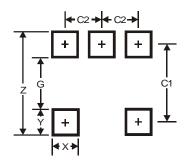
| SOT353 | | | | | |
|----------------------|-----------|------|-------|--|--|
| Dim | Min | Max | Тур | | |
| A 1 | 0.00 | 0.10 | 0.05 | | |
| A2 | 0.90 | 1.00 | 0.95 | | |
| b | 0.10 | 0.30 | 0.25 | | |
| С | 0.10 | 0.22 | 0.11 | | |
| D | 1.80 | 2.20 | 2.15 | | |
| Е | 2.00 | 2.20 | 2.10 | | |
| E1 | 1.15 | 1.35 | 1.30 | | |
| е | 0.650 BSC | | | | |
| F | 0.40 | 0.45 | 0.425 | | |
| L | 0.25 | 0.40 | 0.30 | | |
| а | 0° | 8° | | | |
| All Dimensions in mm | | | | | |



Suggested Pad Layout

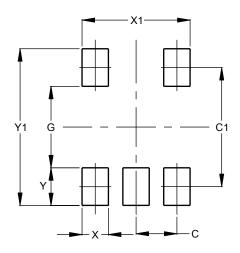
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



| Dimensions | Value |
|------------|-------|
| Z | 3.20 |
| G | 1.60 |
| Х | 0.55 |
| Υ | 0.80 |
| C1 | 2.40 |
| C2 | 0.95 |

(2) Package Type: SOT353



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.650 |
| C1 | 1.900 |
| G | 1.300 |
| Х | 0.420 |
| X1 | 1.720 |
| Y | 0.600 |
| Y1 | 2 500 |

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0064 grams (Approximate)



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RHRXH162244K1 74AUP1G34FW5-7 74AUP1G07FW5-7 74LVC1G126FW4-7 74LVC2G126RA3-7 NLX2G17CMUTCG
74LVCE1G125FZ4-7 Le87501NQC 74AUP1G126FW5-7 TC74HC4050AP(F) 74LVCE1G07FZ4-7 NLX3G16DMUTCG
NLX2G06AMUTCG NLVVHC1G50DFT2G LE87100NQC LE87100NQCT LE87290YQC LE87290YQCT LE87511NQC LE87511NQCT
LE87557NQC LE87557NQCT LE87614MQC LE87614MQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG